

SBR2U30P1

2.0A SBR® **SUPER BARRIER RECTIFIER** POWERDI®123

Features

- Ultra Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Interlocking Clip Design for High Surge Current Capacity
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- ±16KV ESD Protection (HBM, 3B)
- ±25KV ESD Protection (IEC61000-4-2 Level 4, Air Discharge)
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Molding Compound (No Br, Sb)
- Qualified to AEC-Q 101 Standards for High Reliability

Mechanical Data

- Case: POWERDI®123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity Indicator: Cathode Band
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.018 grams (approximate)

POWERDI®123



Top View

Ordering Information (Note 2)

Part Number	Case	Packaging
SBR2U30P1-7	POWERDI [®] 123	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2). All applicable RoHS exemptions applied
- 2. For packaging details, go to our website at http://www.diodes.com.

Marking Information



2U3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006)M = Month (ex: 9 = September)

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	T	U	V	W	Χ	Υ	Z	Α	В	С	D	Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings @TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		
Working Peak Reverse Voltage	V_{RWM}	30	V
DC Blocking Voltage	V_{RM}		
RMS Reverse Voltage	V _{R(RMS)}	21	V
Average Rectified Output Current (See Figure 1)	I _O	2.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms	I _{FSM}	75	Α
Single Half Sine-Wave Superimposed on Rated Load	-i Olvi	-	
Non-Repetitive Avalanche Energy	EAS	105	mJ
$(T_J = 25^{\circ}C, I_{AS} = 5A, L = 8.5 \text{ mH})$	⊏AS	103	1113
Repetitive Peak Avalanche Energy	D	1100	W
$(T_P = 1\mu s, T_J = 25^{\circ}C)$	P _{ARM}	1100	VV

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Soldering (Note 3) Thermal Resistance Junction to Ambient (Note 4) Thermal Resistance Junction to Ambient (Note 5)	$egin{array}{c} {\sf R}_{ heta {\sf JS}} \ {\sf R}_{ heta {\sf JA}} \ {\sf R}_{ heta {\sf JA}} \end{array}$	5 178 123	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

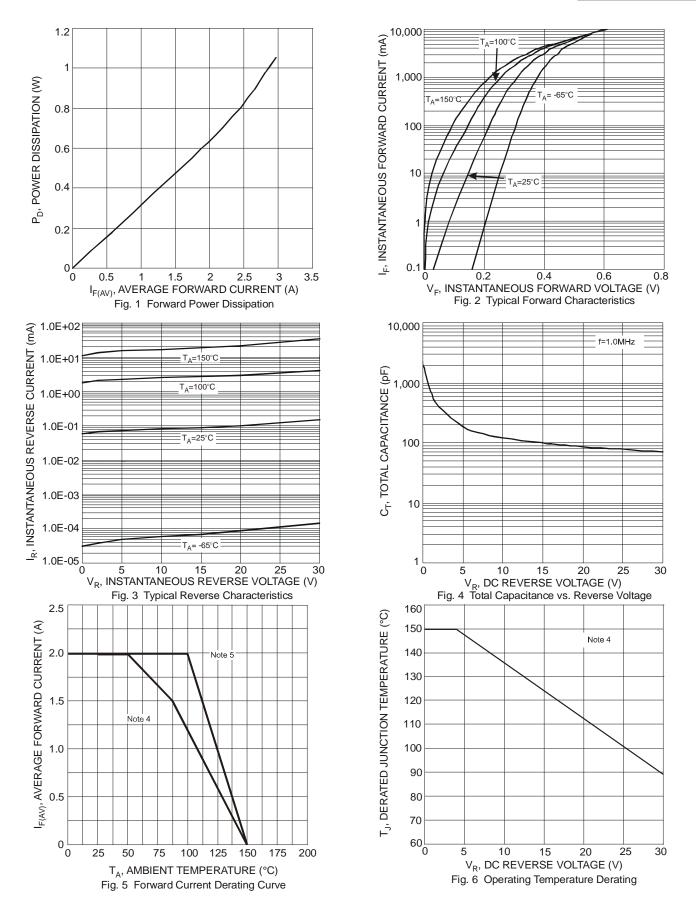
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	$V_{(BR)R}$	30	=	-	V	$I_R = 400\mu A$
	V _F	-	0.22	0.26	٧	$I_F = 0.1A, T_J = 25^{\circ}C$
		-	0.31	0.35		$I_F = 1.0A, T_J = 25^{\circ}C$
Forward Voltage Drop		-	0.36	0.40		$I_F = 2.0A$, $T_J = 25^{\circ}C$
		-	0.12	0.15		$I_F = 0.1A, T_J = 125^{\circ}C$
		-	0.27	0.30		I _F = 1.0A, T _J = 125°C
		-	0.30	0.33		$I_F = 2.0A$, $T_J = 125$ °C
Leakage Current (Note 6)	I _R	-	75	150	μA	$V_R = 5V, T_J = 25^{\circ}C$
		-	150	400	μA	V _R = 30V, T _J = 25°C
		-	6	15	mA	$V_R = 5V, T_J = 125^{\circ}C$
		-	12	20	mA	$V_R = 30V, T_J = 125^{\circ}C$

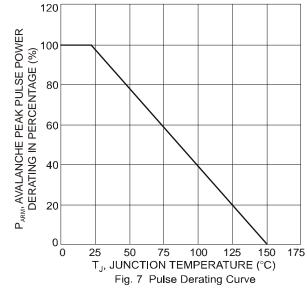
Notes:

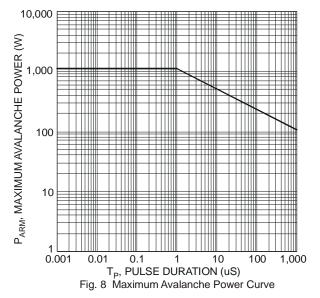
- 3. Theoretical R_{eJS} calculated from the top center of the die straight down to the PCB cathode tab solder junction.
 4. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.
 5. Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.
 6. Short duration pulse test used to minimize self-heating effect.

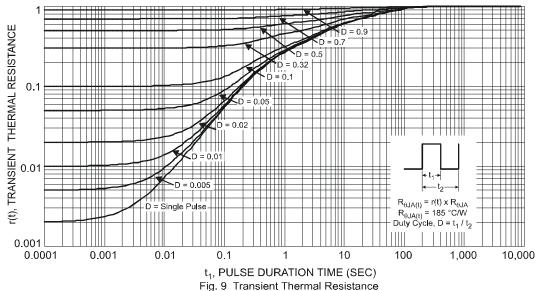




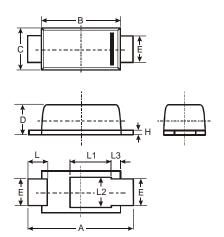








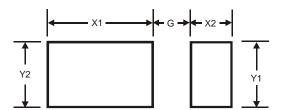
Package Outline Dimensions



POWERDI [®] 123							
Dim	Min	Max	Тур				
Α	3.50	3.90	3.70				
В	2.60	3.00	2.80				
O	1.63	1.93	1.78				
D	0.93	1.00	0.98				
Е	0.85	1.25	1.00				
Н	0.15	0.25	0.20				
L	0.40	0.50	0.45				
L1	-	-	1.35				
L2	-	-	1.10				
L3	-	-	0.20				
All D	All Dimensions in mm						



Suggested Pad Layout



Dimensions	Value (in mm)		
G	1.0		
X1	2.2		
X2	0.9		
Y1	1.4		
Y2	1.4		

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